

# **HD74LS293**

## 4-bit Binary Counter

REJ03D0477-0300 Rev.3.00 Jul.15.2005

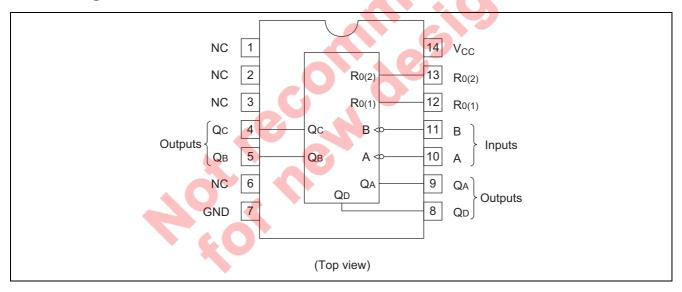
This counter contains four master-slave flip-flops and additional gating to provide a divide-by-two counter and divide-by-eight counter. This counter has a gated zero reset. To use the maximum count length of this counter, the B input is connected to the  $Q_A$  output. The input count pulses are applied to input A and the outputs are as described in the appropriate function table.

#### **Features**

Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LS293P	DILP-14 pin	PRDP0014AB-B (DP-14AV)	Р	_

### **Pin Arrangement**



#### **Function Table**

#### **Reset / Count**

Reset	Input	Outputs				
R <sub>0 (1)</sub>	R <sub>0 (2)</sub>	Q <sub>D</sub> Q <sub>C</sub> Q <sub>B</sub> Q <sub>A</sub>				
Н	Н	L	L	L	L	
L	Х	Count				
X	L	Count				

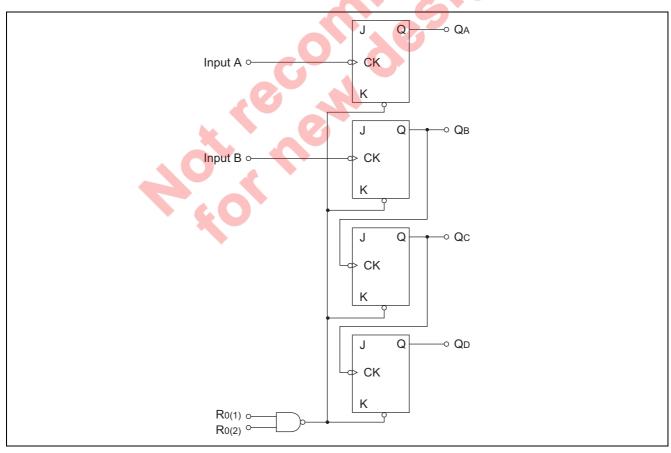
### **BCD Count Sequence**

Count	Outputs								
Count	Q <sub>D</sub>	Q <sub>C</sub>	Q <sub>B</sub>	Q <sub>A</sub>					
0	L	L	L	L					
1	L	L	L	Н					
2	L	L	Н	L					
3	L	L	Н	Н					
4	L	Н	L	L					
5	L	Н	L	Н					
6	L	Н	Н	L					
7	L	Н	Н	Н					
8	Н	L	L	L					
9	Н	L	L	Н					
10	Н	L	Н	L					
11	Н	L	Н	Н					
12	Н	Н	L	L					
13	Н	Н	L	Н					
14	Н	Н	Н	L					
15	Н	Н	Н	Н					

Notes: 1. H; high level, L; low level, X; irrelevant

2. Output  $Q_A$  is connected to input B.

### **Block Diagram**



### **Absolute Maximum Ratings**

Item		Symbol	Ratings	Unit
Supply voltage		V <sub>CC</sub>	7	V
R <sub>O</sub> Inpo		V	7	V
Input voltage	A, B Inputs	$V_{IN}$	5.5	V
Power dissipation		P <sub>T</sub>	400	mW
Operating temperature		Topr	-20 to +75	°C
Storage temperature		Tstg	-65 to +150	°C

Note: Voltage value, unless otherwise noted, are with respect to network ground terminal.

### **Recommended Operating Conditions**

Item		Symbol	Min	Тур	Max	Unit
Supply voltage		Vcc	4.75 5.00		5.25	V
Output current		I <sub>OH</sub>	_	_	-400	μΑ
Output current		I <sub>OL</sub>	_	_	8	mA
Operating temperature		Topr	-20	25	75	°C
Count frequency	A input	fcount	0	- 0	32	MHz
	B input		0		16	IVITIZ
	A input		15			
Pulse width	B input	t <sub>w</sub>	30	<b>(</b> )- <b>N</b>	<u> </u>	ns
ruise widiii	Reset inputs	- t <sub>W</sub>	15		) –	113
Setup time	•	t <sub>su</sub>	25	6	_	ns

#### **Electrical Characteristics**

 $(Ta = -20 \text{ to } +75 \text{ }^{\circ}\text{C})$ 

It	em	Symbol	min.	typ.*	max.	Unit	Condition
Input voltago		ViH	2.0	_	_	V	
iliput voitage	Input voltage		_	(4)	0.8	V	
Output voltos	10	V <sub>OH</sub>	2.7		_	V	$V_{CC} = 4.75 \; V,  V_{IH} = 2 \; V,  V_{IL} = 0.8 \; V, \\ I_{OH} = -400 \; \mu A$
Output voltag	je -	V <sub>OL</sub>	_	_	0.4	V	$I_{OL} = 4 \text{ mA}^{**}$ $V_{CC} = 4.75 \text{ V},$
				_	0.5	V	$I_{OL} = 8 \text{ mA}^{**}$ $V_{IH} = 2 \text{ V}, V_{IL} = 0.8 \text{ V}$
	Any Reset		_	_	20		
	A input	I <sub>IH</sub>	_	_	40	μΑ	$V_{CC} = 5.25 \text{ V}, V_{I} = 2.7 \text{ V}$
	B input		_	_	40		
la mont	Any Reset		_	_	-0.4		
Input current	A input	I <sub>IL</sub>	_	_	-2.4	mA	$V_{CC} = 5.25 \text{ V}, V_{I} = 0.4 \text{ V}$
current	B input		_	_	-1.6		
	Any Reset		_	_	0.1		V <sub>I</sub> = 7 V
	A input	l <sub>l</sub>	_	_	0.2	mA	$V_{I} = 5.5 \text{ V}$ $V_{CC} = 5.25 \text{ V}$
	B input		_	_	0.2		V  = 5.5 V
Short-circuit output current		Ios	-20	_	-100	mA	V <sub>CC</sub> = 5.25 V
Supply current***		Icc	_	9	15	mA	V <sub>CC</sub> = 5.25 V
Input clamp \	/oltage	V <sub>IK</sub>	_	_	-1.5	V	$V_{CC} = 4.75 \text{ V}, I_{IN} = -18 \text{ mA}$

Notes: \* V<sub>CC</sub> = 5 V, Ta = 25°C

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<sup>\*\*</sup>  $Q_A$  output is tested at specified  $I_{OL}$  plus the limit value of  $I_{IL}$  for the B input. This permits driving the B input while maintaining full fan-out capability.

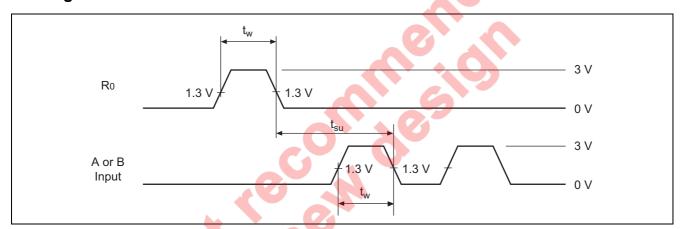
<sup>\*\*\*</sup>  $I_{CC}$  is measured with all outputs open, both  $R_0$  inputs grounded following momentary connection to 4.5 V, and all other inputs grounded.

## **Switching Characteristics**

 $(V_{CC} = 5 \text{ V}, \text{ Ta} = 25^{\circ}\text{C})$ 

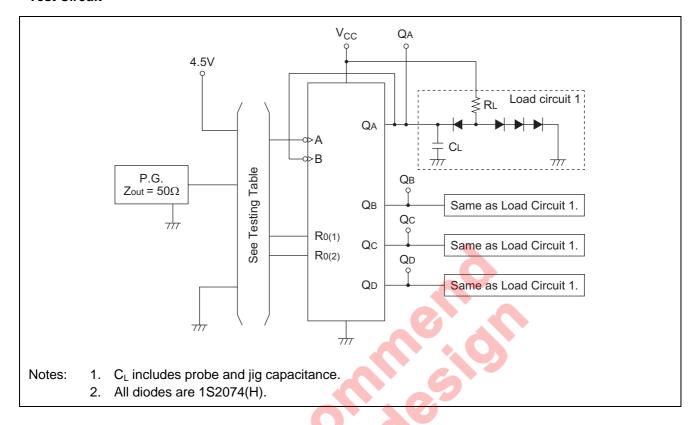
Item	Symbol	Inputs	Outputs	min.	typ.	max.	Unit	Condition
Maximum count	£	Α	$Q_A$	32	42		MHz	
frequency	$f_{\sf max}$	В	Q <sub>B</sub>	16	_		IVII IZ	
	t <sub>PLH</sub>	А	$Q_A$		10	16	ns	
	t <sub>PHL</sub>	^	$\mathbf{Q}_{A}$	_	12	18	113	$C_L = 15 \text{ pF},$ $R_L = 2 \text{ k}\Omega$
	t <sub>PLH</sub>	А	$Q_D$	1	46	70	ns	
	t <sub>PHL</sub>	^			46	70		
Dropogation dolay	t <sub>PLH</sub>	В	Q <sub>B</sub>	_	10	16	ns	
Propagation delay time	t <sub>PHL</sub>	ט			14	21		
ume	t <sub>PLH</sub>	В	$Q_{C}$	1	21	32	ns	
	t <sub>PHL</sub>	ь	Qc	_	23	35		
	t <sub>PLH</sub>	В	$Q_{D}$	_	34	51	ns	
	t <sub>PHL</sub>	ט	<b>Q</b> D		34	51		
	t <sub>PHL</sub>	Set-to-0	Q <sub>A</sub> to Q <sub>D</sub>	_	26	40	ns	

# **Timing Method**



### **Testing Method**

#### **Test Circuit**



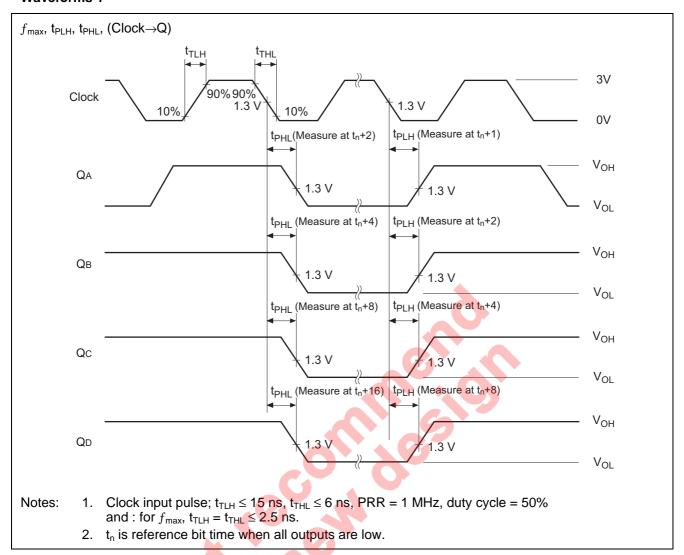
#### **Testing Table**

Item	From input to output	Inputs			Outputs			
	From input to output	Α	В	R₀	$Q_A$	Q <sub>B</sub>	Qc	$\mathbf{Q}_{D}$
£	A→Q	IN	to Q <sub>A</sub>	GND	OUT	OUT	OUT	OUT
$f_{\sf max}$	B→Q	4.5V	IN	GND	_	OUT	OUT	OUT
	$A \rightarrow Q_A$	IN	to Q <sub>A</sub>	GND	OUT	_	_	_
	$A \rightarrow Q_D$	IN	to Q <sub>A</sub>	GND	_	_	_	OUT
$t_{PLH}$	$B \rightarrow Q_B$	4.5V	IN	GND	_	OUT	_	_
$t_{PHL}$	$B \rightarrow Q_C$	4.5V	IN	GND	_	_	OUT	_
Ī	$B \rightarrow Q_D$	4.5V	IN	GND	_	_	_	OUT
	$R_0 \rightarrow Q^{**}$	IN*	to Q <sub>A</sub>	IN	OUT	OUT	OUT	OUT

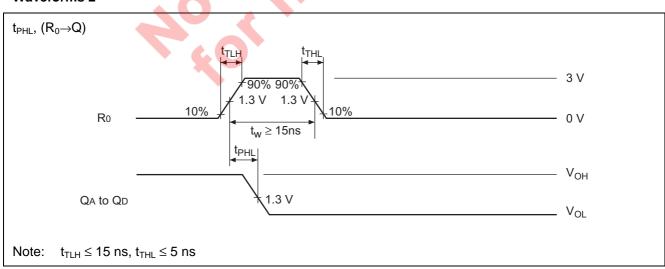
Notes: \* For initialized.

<sup>\*\*</sup> Measured with each input and unused inputs at 4.5 V.

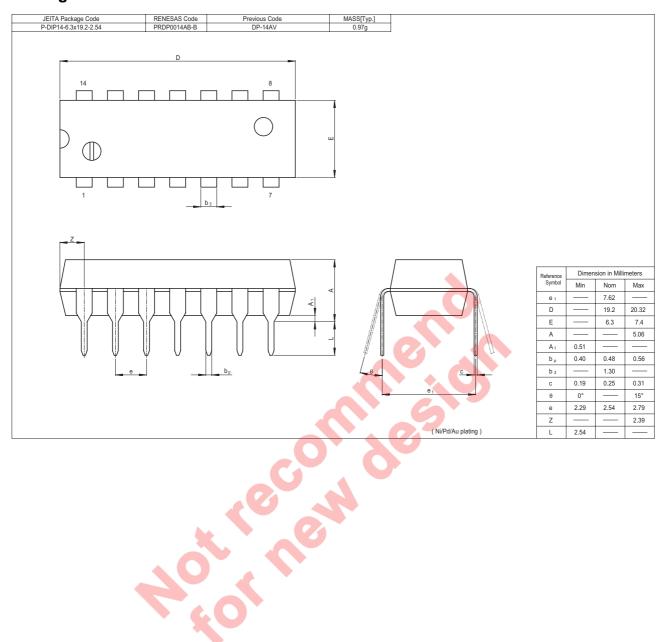
#### Waveforms 1



#### Waveforms 2



### **Package Dimensions**



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